# TinyLogic HS Inverter with Schmitt Trigger Input

# NC7S14

## Description

The NC7S14 is a single high performance CMOS Inverter with Schmitt Trigger input. The circuit design provides hysteresis between the positive–going and negative going input thresholds thereby improving noise margins.

Advanced Silicon Gate CMOS fabrication assures high speed and low power circuit operation over a broad  $V_{CC}$  range. ESD protection diodes inherently guard both input and output with respect to the  $V_{CC}$  and GND rails.

## Features

- Space Saving SC-74A and SC-88A 5-Lead Package
- Ultra Small MicroPak<sup>TM</sup> Leadless Package
- Schmitt Input Hysteresis: >1 V Typ
- High Speed:  $t_{PD} = 4.5$  ns Typ
- Low Quiescent Power:  $I_{CC} < 1 \mu A$
- Balanced Output Drive: 2 mA I<sub>OL</sub>, -2 mA I<sub>OH</sub>
- Broad V<sub>CC</sub> Operating Range: 2 V 6 V
- Balanced Propagation Delays
- Specified for 3 V Operation
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

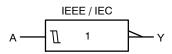
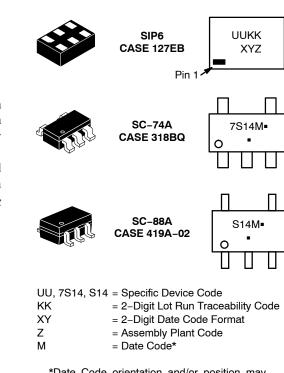


Figure 1. Logic Symbol



\*Date Code orientation and/or position may vary depending upon manufacturing location.

## **ORDERING INFORMATION**

See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

MARKING DIAGRAMS

# **Pin Configurations**

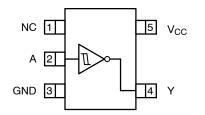
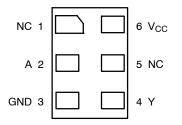


Figure 2. SC-88A and SC-74A (Top View)

#### **PIN DESCRIPTIONS**

Pin Name	Description
А	Input
Y	Output
NC	No Connect



## Figure 3. MicroPak (Top Through View)

## **FUNCTION TABLE** $(Y = \overline{A})$

Input	Output
A	Y
L	Н
Н	L

H = HIGH Logic Level L = LOW Logic Level

#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Paran	neter	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage		-0.5	6.5	V
I <sub>IK</sub>	DC Input Diode Current	V <sub>IN</sub> < 0 V	-	-20	mA
		$V_{IN} > V_{CC}$	-	+20	
V <sub>IN</sub>	DC Input Voltage		-0.5	V <sub>CC</sub> + 0.5	V
I <sub>OK</sub>	DC Output Diode Current V <sub>OUT</sub> < 0 V		-	-20	mA
		V <sub>OUT</sub> > V <sub>CC</sub>	-	+20	
V <sub>OUT</sub>	DC Output Voltage		-0.5	V <sub>CC</sub> + 0.5	V
I <sub>OUT</sub>	DC Output Source or Sink Current		-	±12.5	mA
$I_{CC} \text{ or } I_{GND}$	DC V <sub>CC</sub> or Ground Current per Output Pin		-	±25	mA
T <sub>STG</sub>	Storage Temperature		-65	+150	°C
TJ	Junction Temperature		-	+150	°C
ΤL	Lead Temperature (Soldering, 10 Seconds)		-	+260	°C
PD	Power Dissipation in Still Air	SC-74A	-	390	mW
		SC-88A	-	332	7
		MicroPak-6	-	812	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

## **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Conditions	Min	Мах	Unit
V <sub>CC</sub>	Supply Voltage		2.0	6.0	V
V <sub>IN</sub>	Input Voltage		0	V <sub>CC</sub>	V
V <sub>OUT</sub>	Output Voltage		0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature		-40	+85	°C
$\theta_{JA}$	Thermal Resistance	SC-74A	-	320	°C/W
		SC-88A	-	377	
		MicroPak-6	-	154	

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability. 1. Unused inputs must be held HIGH or LOW. They may not float.

## DC ELECTICAL CHARACTERISTICS

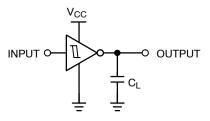
				T <sub>A</sub> = +25°C			T <sub>A</sub> = -40	to +85°C	
Symbol	Parameter	V <sub>CC</sub> (V)	Conditions	Min	Тур	Max	Min	Max	Unit
VP	Positive Threshold Voltage	2.0 3.0 4.5 6.0		- - - -	1.29 1.90 2.73 3.56	1.5 2.2 3.15 4.2	- - - -	1.6 2.2 3.15 4.2	V
V <sub>N</sub>	Negative Threshold Voltage	2.0 3.0 4.5 6.0		0.3 0.6 1.13 1.5	0.70 1.05 1.66 2.24	- - -	0.3 0.6 1.13 1.5		V
V <sub>H</sub>	Hysteresis Voltage	2.0 3.0 4.5 6.0		0.3 0.4 0.6 0.8	0.59 0.85 1.08 1.31	1.0 1.3 1.4 1.7	0.3 0.4 0.6 0.8	1.0 1.3 1.4 1.7	V
V <sub>OH</sub>	HIGH Level Output Voltage	2.0 3.0 4.5 6.0	$I_{OH} = -20 \ \mu A$ $V_{IN} = V_{IH} \text{ or } V_{IL}$	1.90 2.90 4.40 5.90	2.0 3.0 4.5 6.0	- - -	1.90 2.90 4.40 5.90	- - - -	V
		3.0 4.5 6.0	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -1.3 \text{ mA}$ $I_{OH} = -2.0 \text{ mA}$ $I_{OH} = -2.6 \text{ mA}$	2.68 4.18 5.68	2.87 4.37 5.86	- - -	2.63 4.13 5.63	- - -	V
V <sub>OL</sub>	LOW Level Output Voltage	2.0 3.0 4.5 6.0	$I_{OL} = 20 \ \mu A$ $V_{IN} = V_{IH} \text{ or } V_{IL}$	- - -	0.0 0.0 0.0 0.0	0.10 0.10 0.10 0.10		0.10 0.10 0.10 0.10	V
		3.0 4.5 6.0	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 1.3 \text{ mA}$ $I_{OL} = 2.0 \text{ mA}$ $I_{OL} = 2.6 \text{ mA}$	- - -	0.1 0.1 0.1	0.26 0.26 0.26	- - -	0.33 0.33 0.33	V
I <sub>IN</sub>	Input Leakage Current	6.0	$V_{IN} = V_{CC}, \text{ GND}$	-	-	±0.1	-	±1.0	μA
I <sub>CC</sub>	Quiescent Supply Current	6.0	$V_{IN} = V_{CC}, \text{ GND}$	-	-	1.0	-	10.0	μA

# AC ELECTRICAL CHARACTERISTICS

		T <sub>A</sub> = +25°C T <sub>A</sub> = -40	T <sub>A</sub> = +25°C		T <sub>A</sub> = -40	to +85°C			
Symbol	Parameter	V <sub>CC</sub> (V)	Conditions	Min	Тур	Max	Min	Max	Unit
t <sub>PLH,</sub>	Propagation Delay (Figure 4, 6)	5.0	C <sub>L</sub> = 15 pF	-	4.5	21	-	-	ns
<sup>t</sup> PHL		2.0 3.0 4.5 6.0	C <sub>L</sub> = 50 pF		20 12 8.5 7.5	100 27 20 17	- - -	125 35 25 21	ns
t <sub>TLH,</sub>	Output Transition Time	5.0	C <sub>L</sub> = 15 pF	-	3	8	-	-	ns
t <sub>THL</sub>	(Figure 4, 6)	2.0 3.0 4.5 6.0	C <sub>L</sub> = 50 pF	- - -	25 16 11 9	125 35 25 21	- - - -	145 45 30 24	ns
C <sub>IN</sub>	Input Capacitance	Open		-	2	10	-	10	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Figure 5)	5.0	(Note 2)	-	7	_	_	-	pF

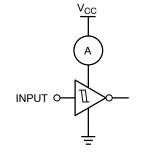
 C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I<sub>CCD</sub>) at no output loading and operating at 50% duty cycle. C<sub>PD</sub> is related to I<sub>CCD</sub> dynamic operating current by the expression: I<sub>CCD</sub> = (C<sub>PD</sub>) (V<sub>CC</sub>) (f<sub>IN</sub>) + (I<sub>CC</sub>static).

### AC Loading and Waveforms



 $C_L$  includes load and stray capacitance Input PRR = 1.0 MHz;  $t_W$  = 500 ns

### Figure 4. AC Test Circuit



Input = AC Waveforms; PRR = Variable; Duty Cycle = 50%.

Figure 5. I<sub>CCD</sub> Test Circuit

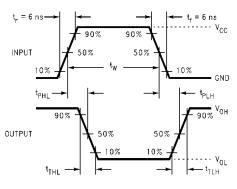


Figure 6. AC Waveforms

#### **ORDERING INFORMATION**

Part Number	Top Mark	Package Description	Shipping <sup>†</sup>
NC7S14M5X	7S14	SC-74A	3000 / Tape & Reel
NC7S14P5X	S14	SC-88A	3000 / Tape & Reel
NC7S14P5X-L22057	S14	SC-88A	3000 / Tape & Reel
NC7S14L6X	UU	SIP6, MicroPak	5000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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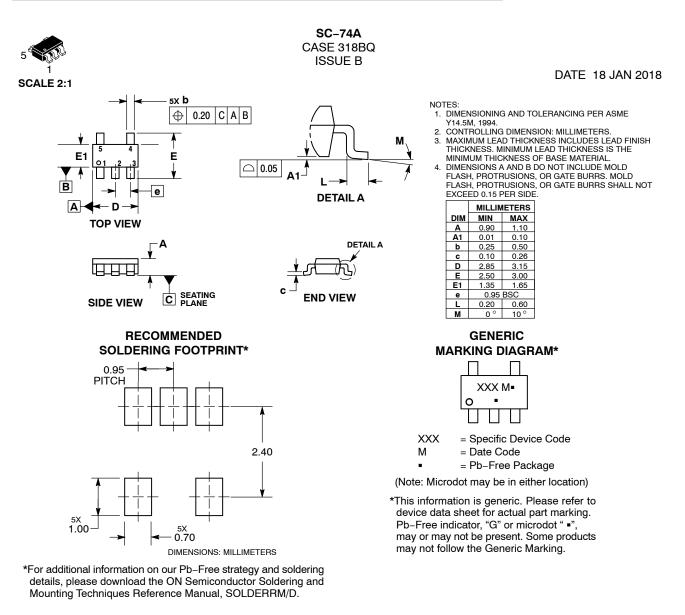


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